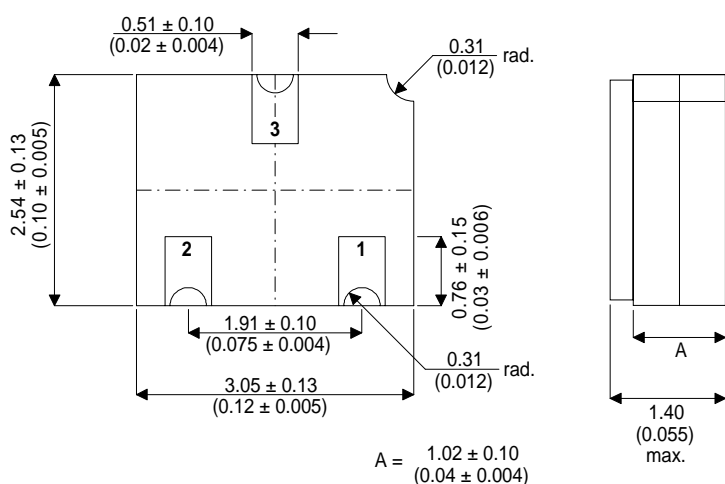


MECHANICAL DATA

Dimensions in mm (inches)



SILICON EPITAXIAL PLANAR DIODE

Fast Switching Diode in
Hermetic Ceramic Surface Mount Package
For High Reliability Applications

SOT23 CERAMIC (LCC1 PACKAGE)

Underside View

PAD 1 — Anode PAD 2 — Not Connected PAD 3 — Cathode

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_R	Reverse Voltage			75	V
V_{RRM}	Repetitive Peak Reverse Voltage			75	V
$I_{F(AV)}$	Average Rectified Forward Current			150	mA
I_F	Forward Current			200	mA
I_{FRM}	Repetitive Peak Forward Current			450	mA
I_{FSM}	Non-Repetitive Peak Forward Current	$t = 1\mu s$		2000	mA
		$t = 1s$		500	
P_{tot}	Power Dissipation at $T_{amb} = 25^{\circ}C$			500	mW

T_{stg}	Storage Temperature Range	-55 to +175 °C
T_j	Max junction temperature	+150°C

CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_F Forward Voltage	$I_F = 10mA$			1	V
I_R Reverse Current	$V_R = 20V$			25	nA
	$V_R = 20V, T_j = 150^{\circ}C$			50	μA
$V_{(BR)R}$ Reverse Avalanche Breakdown Voltage	$I_R = 100\mu A$	100			V
	$I_R = 5\mu A$	75			V
C_d Capacitance	$V_R = 0V, f = 1 MHz$			4	pF
V_{fr} Forward Recovery Voltage	$I_F = 50mA, t_r = 20ns$			2.5	V
t_{rr} Reverse Recovery Time	$I_F = 10mA$ to $I_R = 60mA$ $R_L = 100\Omega$			4	ns



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